

www.ti.com SLOS700 – JANUARY 2011

DirectPath™ 2.5-mW Headphone Amplifier With Programmable-Fixed Gain

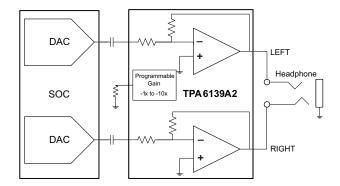
Check for Samples: TPA6139A2

FEATURES

- DirectPath™
 - Eliminates Pop/Clicks
 - Eliminates Output DC-Blocking Capacitors
 - 3 V to 3.6 V Supply voltage
- Low Noise and THD
 - SNR > 105 dB at -1x Gain
 - Typical Vn < 15 μVms 20-20kHz at -1x Gain
 - THD+N < 0.003% at 10kΩ Load and -1x Gain
- 25 mW into 600 Ω Load
- 2 Vrms Output Voltage into 5kΩ Load
- Single Ended Input and Output
- Programmable Gain Select Reduces Component Count
 - 13x Gain Values
- Active Mute With More Than 80dB Attenuation
- Short Circuit and Thermal Protection
- ±8kV HBM ESD Protected Outputs

APPLICATIONS

- PDP / LCD TV
- Blu-ray Disc™, DVD Players
- Mini/Micro Combo Systems
- Soundcards



DESCRIPTION

The TPA6139A2PW is a 25mW Pop-Free stereo Head Phone driver designed to reduce component count, board space and cost. It is ideal for single supply electronics where size and cost are critical design parameters.

TPA6139A2

The TPA6139A2 does not require a power supply greater than 3.3V to generate its 25mW, nor does it require a split rail power supply.

Designed using Tl's patented DIRECTPATHTM technology which integrates a charge pump to generate a negative supply rail that provides a clean, pop-free ground biased output. The TPA6139A2 is capable of driving 25mW into 32 Ω and 2Vms into a 600 Ω load. DIRECTPATH also allows the removal of the costly output DC-blocking capacitors.

The device has fixed gain single ended inputs with a gain select pin. Using a single resistor on this pin, the designer can choose from 13 internal programmable gain settings to match the line driver with the Codec output level. It also reduces the component count and board space.

Headphone outputs have ±8kV HBM ESD protection enabling a simple ESD protection circuit. The TPA6139A2 has built-in active mute control with more that 80dB attenuation for pop-free mute on/off control.

The TPA6139A2 is available in a 14-pin TSSOP and a 16-pin QFN. For a pin compatible 2vrms line driver see DRV612.

AV.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

DirectPath, DIRECTPATH are trademarks of Texas Instruments. Blu-ray Disc is a trademark of Blu-ray Disc Association.

SLOS700 – JANUARY 2011 www.ti.com



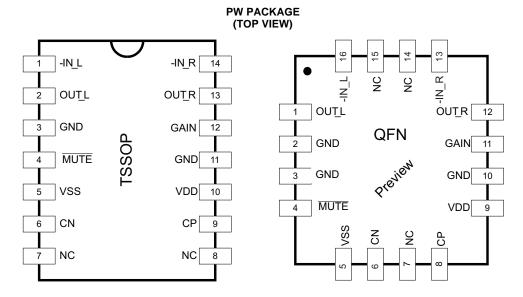


These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

GENERAL INFORMATION

PIN ASSIGNMENT

The TPA6139A2 is available in a 14-pin TSSOP package (PW) or 16-pin QFN package (RGT- Preview)



PIN FUNCTIONS

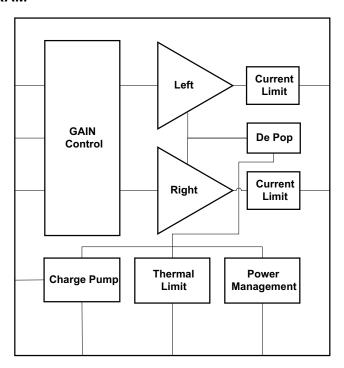
	PIN		FUNCTION ⁽¹⁾	DESCRIPTION
NAME	PW NO.	RGT NO.		
-IN_L	1	16	1	Negative input, left channel
OUT_L	2	1	0	Output, left channel
GND	3, 11	2, 3, 10	Р	Ground
MUTE	4	4	I	MUTE, active low
VSS	5	5	0	Change Pump negative supply voltage
CN	6	6	I/O	Charge Pump flying capacitor negative connection
NC	7, 8	7. 14, 15		No internal connection
СР	9	8	I/O	Charge Pump flying capacitor positive connection
VDD	10	9	Р	Supply voltage, connect to positive supply
GAIN	12	11	I	Gain set programming pin; connect a resistor to ground. See Table 1 for recommended resistor values
OUT_R	13	12	0	Output, right channel
-IN_R	14	13	I	Negative input, right channel

(1) I = input, O = output, P = power



www.ti.com

SYSTEM BLOCK DIAGRAM



ORDERING INFORMATION(1)

T _A	PACKAGE	DESCRIPTION
-40°C to 85°C	TPA6139A2PW	14-pin TSSOP
-40°C to 85°C	TPA6139A2RGT	16-pin QFN

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

THERMAL INFORMATION

	THERMAL METRIC ⁽¹⁾	TPA6139A2 PW (14-Pin)	TPA6139A2 RGT (16-Pin)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	130	52	
θ_{JCtop}	Junction-to-case (top) thermal resistance	49	71	
θ_{JB}	Junction-to-board thermal resistance	63	26	900
ΨЈТ	Junction-to-top characterization parameter	3.6	3.0	°C/W
ΨЈВ	Junction-to-board characterization parameter	62	26	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	N/A	9.8	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

	,	VALUE	UNIT	
VDD to GND		-0.3 to 4	V	
Input voltage, V _I		VSS-0.3 to VDD+0.3	V	
MUTE to GND		-0.3 to VDD+0.3	V	
Maximum operating junc	ction temperature range, T _J	-40 to 150	°C	
Storage temperature		-40 to 150	°C	
Lead temperature		260		
ESD Protection – HBM	OUT_L, OUT_R	8	kV	
	All other pins	2	kV	

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range unless otherwise noted

			MIN	NOM	MAX	UNIT
VDD	Supply voltage	DC supply voltage	3.0	3.3	3.6	V
R_{L}				5		kΩ
V_{IL}	Low-level input voltage	MUTE	38	40	43	%PVDD
V _{IH}	High-level input voltage	MUTE	57	60	66	%PVDD
T _A	Free-air temperature		-40	25	85	°C



www.ti.com

ELECTRICAL CHARACTERISTICS

VDD = 3.3V, R_{Load} = 32 Ω , T_A = 25°C, Charge pump: C_{CP} = 1.0 μF (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V _{os}	Output offset voltage	VDD = 3.3 V, input ac-coupled		0.5	1	mV	
PSRR	Power-supply rejection ratio		70	80		dB	
V _{OH}	High-level output voltage	VDD = 3.3 V	3.1			V	
V _{OL}	Low-level output voltage	VDD = 3.3 V			-3.05	V	
Vuvp_on	PVDD, under voltage detection				2.8	V	
Vuvp_hysteresis	PVDD, under voltage detection, hysteresis			200		mV	
Fcp	Charge pump switching frequency			350		kHz	
I _{IH}	High-level input current, MUTE	VDD = 3.3 V, V _{IH} = VDD			1	μΑ	
I _{IL}	Low-level input current, MUTE	VDD = 3.3 V, V _{IL} = 0 V			1	μΑ	
I (VDD)	Supply current, no load	VDD, MUTE = 3.3 V		25		mA	
	Supply current, MUTED	VDD = 3.3 V, MUTE = GND		25		mA	
Tsd	Thermal shutdown			150		°C	
	Thermal shutdown hysteresis			15		°C	
Po	Output Power, outputs in phase	THD+N = 1%, f = 1kHz, 32Ω load		25		mW	
	Output Valence autoute in about	THD+N = 1%, f = 1kHz, 32Ω load		0.9			
V _O	Output Voltage, outputs in phase	THD+N = 1%, f = 1kHz, 600Ω load		2.0		V_{rms}	
THD+N	Total Harmonic distortion plus noise	$f = 1kHz$, 32Ω load, Po= 25mW, -1x gain		0.03%			
THD+N	Total Harmonic distortion plus noise	f = 1kHz, 10kΩload, Vo=2 Vrms, -1x gain	(0.005%			
ΔA_{V}	Gain matching	Between left and right channels		0.25		dB	
Z _O	Output impedance when muted	MUTE = GND			1	Ω	
	Input to output attenuation when muted	MUTE = GND		80		dB	
SNR	Signal to noise ratio	A-weighted, AES17 filter, 1Vrms ref 32Ω load, -1x gain		99		dB	
	Signal to noise ratio	A-weighted, AES17 filter, 2Vrms ref 600Ω load, -1x gain		105		dB	
V _n	Noise voltage	A-weighted, AES17 filter, Gain=-2x		12		μV	
	Slew rate			4.5		V/µs	
Gbw	Unity Gain bandwidth			8		MHz	
Crosstalk	Channel to channel	f = 1kHz, Rload = 32Ω, Po= 25mW		-85		dB	
Vincm_pos	Positive Common mode input voltage			+2.0		V	
Vincm_neg	Negative Common mode input voltage			-2.0		V	
I _{lim}	Output current limit			60		mA	



PROGRAMMABLE GAIN SETTINGS

 V_{DD} = 3.3 V, R_{load} = 32 k Ω , T_A = 25°C, Charge pump:= C_{CP} 1 μ F, C_{IN} = 1.0 μ F, 1 x gain select (unless otherwise noted)⁽¹⁾

DADAMETED		TEST CONDITIONS	TP			
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
R_Tol	Gain programming resistor tolerance				2%	
ΔA_V	Gain matching	Between left and right channels		0.25		dB
	Gain step tolerance			0.10		dB
		Gain resistor 2% tolerance 249k or higher 82k0 49k2 35k1		-2.0 -1.0 -1.5 -2.3		
	Gain steps	27k3 20k5 15k4 11k5 9k09		-2.3 -2.5 -3.0 -3.5 -4.0 -5.0		V/V
		7k50 6k19 5k11 3k90		-5.6 -6.4 -8.3 -10.0		
	Input impedance	Gain resistor 2% tolerance 249k or higher 82k0 49k2 35k1 27k3 20k5 15k4 11k5 9k09 7k50 6k19 5k11 3k90		37 55 44 33 31 28 24 22 18 17 15 12		kΩ

⁽¹⁾ If pin 12, GAIN, is left floating an internal pull-up sets the gain to -2.0x Gain setting is latched during power-up

2

3



www.ti.com

TYPICAL CHARACTERISTICS, LINE DRIVER

 $V_{DD}=3.3~V,~T_{A}=25^{\circ}C,~R_{L}=2.5~k\Omega,~C_{PUMP}=C_{(VSS)}=10~\mu\text{F},~R_{IN}=10~k\Omega,~R_{fb}=20~k\Omega~\text{(unless otherwise noted)}$

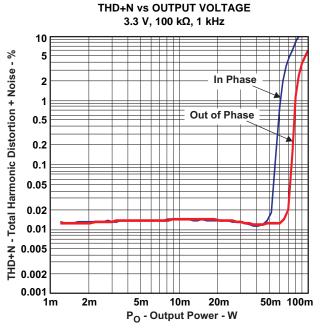
10

0.5

0.002 0.001

200m

300m



THD+N - Total Harmonic Distortion + Noise - % 600R load 0.2 0.1 0.05 0.02 0.01 0.005

THD+N vs OUTPUT VOLTAGE

3.3 V, 600 Ω load, 1 kHz

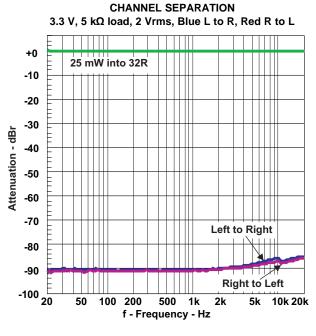
32R load

Figure 2.

500m 700m 1

VO - Output Voltage - V





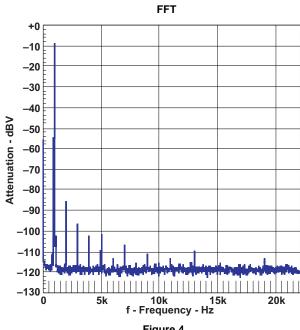


Figure 3.

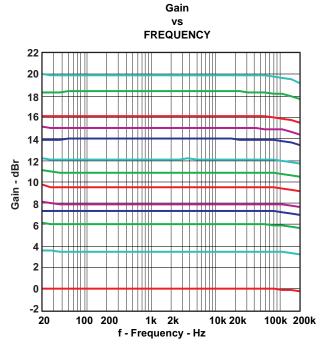
Figure 4.

SLOS700 – JANUARY 2011 www.ti.com

TEXAS INSTRUMENTS

TYPICAL CHARACTERISTICS, LINE DRIVER (continued)

 $V_{DD}=3.3~V,~T_{A}=25^{\circ}C,~R_{L}=2.5~k\Omega,~C_{PUMP}=C_{(VSS)}=10~\mu\text{F},~R_{IN}=10~k\Omega,~R_{fb}=20~k\Omega~\text{(unless otherwise noted)}$



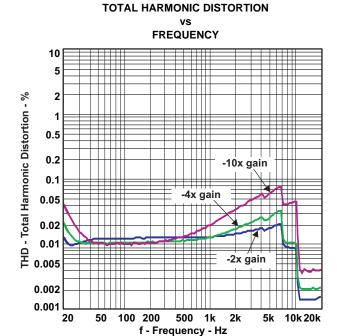


Figure 5.

MUTE TO UN-MUTE

Figure 6.

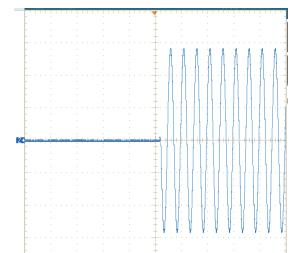


Figure 7.

M 4.0ms 1.25MS/s A Ch1 / 1.72Y

800ns/pt

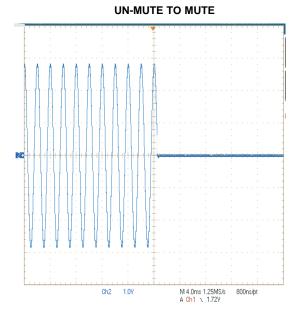


Figure 8.



SLOS700 - JANUARY 2011 www.ti.com

APPLICATION INFORMATION

LINE DRIVER AMPLIFIERS

Single-supply line-driver amplifiers typically require dc-blocking capacitors. The top drawing in Figure 9 illustrates the conventional line-driver amplifier connection to the load and output signal.

DC blocking capacitors are often large in value, and a mute circuit is needed during power up to minimize click and pop. The output capacitor and mute circuit consume PCB area and increase cost of assembly, and can reduce the fidelity of the audio output signal.

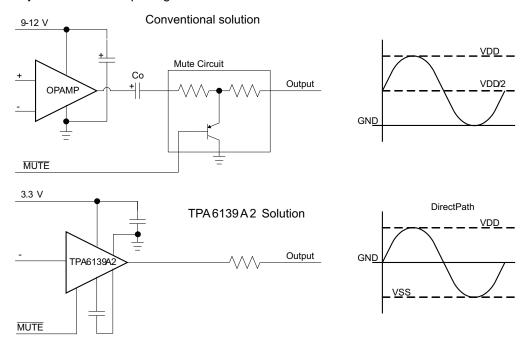


Figure 9. Conventional and DirectPath Line Driver

The DirectPath™ amplifier architecture operates from a single supply but makes use of an internal charge pump to provide a negative voltage rail.

Combining the user-provided positive rail and the negative rail generated by the IC, the device operates in what is effectively a split supply mode.

The output voltages are now centered at zero volts with the capability to swing to the positive rail or negative rail. Combining this with the built-in click and pop reduction circuit, the DirectPath™ amplifier requires no output dc blocking capacitors.

The bottom block diagram and waveform of Figure 9 illustrate the ground-referenced line-driver architecture. This is the architecture of the TPA6139A2.

TEXAS INSTRUMENTS

COMPONENT SELECTION

Charge Pump

The charge pump flying capacitor serves to transfer charge during the generation of the negative supply voltage. The VSS capacitor must be at least equal to the charge pump capacitor in order to allow maximum charge transfer. Low ESR capacitors are an ideal selection, and a value of $1\mu F$ is typical. Capacitor values that are smaller than $1\mu F$ cannot be recommended as it limits the negative voltage swing in low impedance loads.

Decoupling Capacitors

The TPA6139A2 is a DirectPathTM amplifier that requires adequate power supply decoupling to ensure that the noise and total harmonic distortion (THD) are low. A good low equivalent-series-resistance (ESR) ceramic capacitor, typically $1\mu F$, placed as close as possible to the device VDD leads works best. Placing this decoupling capacitor close to the TPA6139A2 is important for the performance of the amplifier. For filtering lower frequency noise signals, a 10- μF or greater capacitor placed near the audio power amplifier also helps, but it is not required in most applications because of the high PSRR of this device.

Gain-Setting

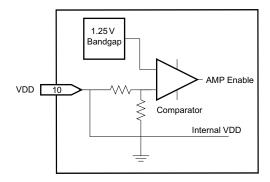
The gain setting is programmed with the GAIN pin individually for line driver and headphone section. Gain setting is latched when the MUTE pin is set high. Table 1 lists the gain settings. The default gain with the gain-set pin left open is -2x.

rabio ii cam counige										
GAIN	GAIN (dB)	INPUT RESISTANCE								
-2.0x	6.0	37k								
-1.0x	0.0	55k								
-1.5x	3.5	44k								
-2.3x	7.2	33k								
-2.5x	8.0	31k								
-3.0x	9.5	28k								
-3.5x	10.9	24k								
-4.0x	12.0	22k								
-5.0x	14.0	18k								
−5.6x	15.0	17k								
-6.4x	16.1	15k								
-8.3x	18.4	12k								
-10x	20.0	10k								
	GAIN -2.0x -1.0x -1.5x -2.3x -2.5x -3.0x -3.5x -4.0x -5.0x -5.6x -6.4x -8.3x	GAIN GAIN (dB) -2.0x 6.0 -1.0x 0.0 -1.5x 3.5 -2.3x 7.2 -2.5x 8.0 -3.0x 9.5 -3.5x 10.9 -4.0x 12.0 -5.0x 14.0 -5.6x 15.0 -6.4x 16.1 -8.3x 18.4								

Table 1. Gain Settings

Internal Under Voltage Detection

The TPA6139A2 contains an internal precision band gap reference voltage and a comparator used to monitor the supply voltage, VDD. The internal VDD monitor is set at 2.8V with 200mV hysteresis.



0 Submit Documentation Feedback



www.ti.com

Input-Blocking Capacitors

DC input-blocking capacitors are required to be added in series with the audio signal into the input pins of the TPA6139A2. These capacitors block the dc portion of the audio source and allow the TPA6139A2 inputs to be properly biased to provide maximum performance. The input blocking capacitors also limit the DC gain to 1, limiting the DC-offset voltage at the output.

These capacitors form a high-pass filter with the input resistor, R_{IN} . The cutoff frequency is calculated using Equation 1. For this calculation, the capacitance used is the input-blocking capacitor and the resistance is the input resistor chosen from Table 1. Then the frequency and/or capacitance can be determined when one of the two values is given.

$$fc_{IN} = \frac{1}{2\pi R_{IN} C_{IN}}$$
 or $C_{IN} = \frac{1}{2\pi fc_{IN} R_{IN}}$ (1)

For a fixed cutoff frequency of 2Hz the size of the input capacitance is shown in the table below with the capacitors rounded up to nearest E6 values. For 20Hz cutoff simply divide the capacitor values with 10; e.g., for 1x gain, 150nF is needed.

Gain_set RESISTOR	GAIN	Gain (dB)	INPUT RESISTANCE	2 Hz Cutoff							
249k	-2.0x	6.0	37k	2.2 µF							
82k0	-1.0x	0.0	55k	1.5 µF							
49k2	-1.5x	3.5	44k	2.2 µF							
35k1	-2.3x	7.2	33k	3.3 µF							
27k3	-2.5x	8.0	31k	3.3 µF							
20k5	-3.0x	9.5	28k	3.3 µF							
15k4	-3.5x	10.9	24k	3.3 µF							
11k5	-4.0x	12.0	22k	4.7 µF							
9k09	-5.0x	14.0	18k	4.7 µF							
7k50	-5.6x	15.0	17k	4.7 µF							
6k19	−6.4x	16.1	15k	6.8 µF							
5k11	-8.3x	18.4	12k	6.8 µF							
3k90	-10x	20.0	10k	10 μF							

Table 2. Input Capacitor for Different Gain and Cutoff

Pop-Free Power Up

Pop-free power up is ensured by keeping the MUTE low during power supply ramp up and down. The pin should be kept low until the input AC-coupling capacitors are fully charged before asserting the MUTE pin high to pre-charge the ac-coupling; and, pop-less power-up is achieved. Figure 10 illustrates the preferred sequence.

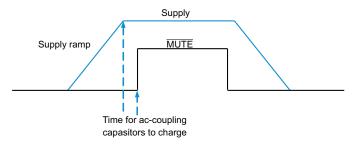


Figure 10. Power-Up Sequence

Copyright © 2011, Texas Instruments Incorporated

SLOS700 – JANUARY 2011 www.ti.com

TEXAS INSTRUMENTS

CAPACITIVE LOAD

The TPA6139A2 has the ability to drive a high capacitive load up to 220 pF directly. Higher capacitive loads can be accepted by adding a series resistor of 47 Ω or larger for the line driver output.

LAYOUT RECOMMENDATIONS

A proposed layout for the TPA6139A2 can be seen in the TPA6139A2EVM User's Guide (SLOU248), and the Gerber files can be downloaded from http://focus.ti.com/docs/toolsw/folders/print/TPA6139A2evm.html. To access this information, open the TPA6139A2 product folder and look in the Tools and Software folder.

Ground traces are recommended to be routed as a star ground to minimize hum interference. VDD, VSS decoupling capacitors and the charge pump capacitors should be connected with short traces.

PIN COMPATIBLE WITH THE DRV612

The TPA6139A2 stereo Headphone amplifier is pin compatible with the DRV612. A single PCB layout can therefore be used with stuffing options for different board configurations.

APPLICATION CIRCUIT

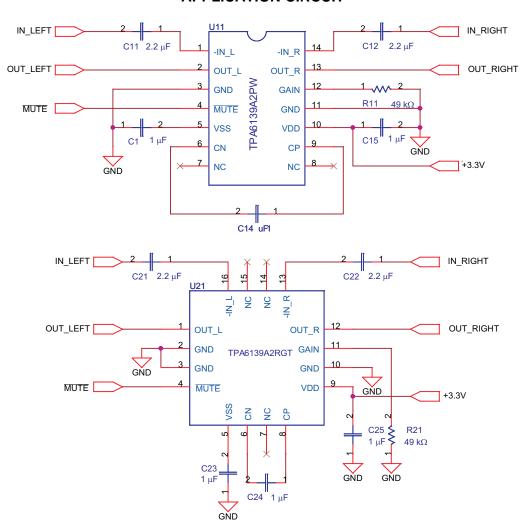


Figure 11. Single Ended Input and Output, Gain Set to -1.5x

12



PACKAGE OPTION ADDENDUM

4-Feb-2011

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
TPA6139A2PW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
TPA6139A2PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

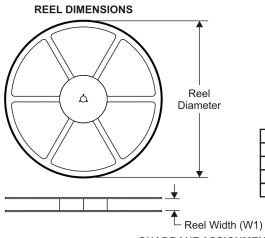
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

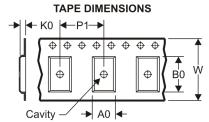
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 8-Feb-2011

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA6139A2PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

www.ti.com 8-Feb-2011



*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
I	TPA6139A2PWR	TSSOP	PW	14	2000	346.0	346.0	29.0

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



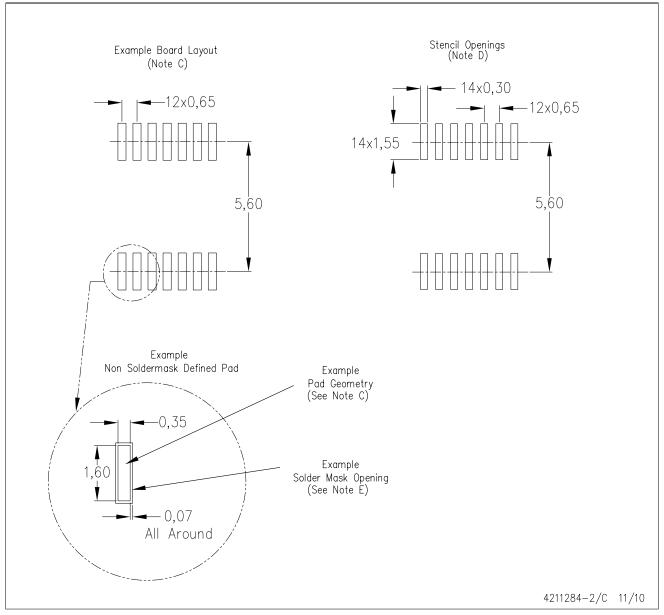
NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications		
Audio	www.ti.com/audio	Communications and Telecom	www.ti.com/communications	
Amplifiers	amplifier.ti.com	Computers and Peripherals	www.ti.com/computers	
Data Converters	dataconverter.ti.com	Consumer Electronics	www.ti.com/consumer-apps	
DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy	
DSP	dsp.ti.com	Industrial	www.ti.com/industrial	
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical	
Interface	interface.ti.com	Security	www.ti.com/security	
Logic	logic.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense	
Power Mgmt	power.ti.com	Transportation and Automotive	www.ti.com/automotive	
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video	
RFID	www.ti-rfid.com	Wireless	www.ti.com/wireless-apps	
RF/IF and ZigBee® Solutions	www.ti.com/lprf			

TI E2E Community Home Page

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated

e2e.ti.com